

REMARKS

At the outset, the Examiner is thanked for the thorough review and consideration of the pending application. The Office Action dated March 4, 2009 has been received and its contents carefully reviewed.

By this response, claim 27 has been amended. No new matter has been added. Thus, claims 27 and 33 are pending in the application. Reconsideration and withdrawal of the rejections are respectfully requested in view of the above amendments and the following remarks.

In the Office Action, claims 27 and 33 are rejected under 35 U.S.C. § 103(a) as being unpatentable over U.S. Patent No. 6,147,667 to Yamazaki et al. (hereinafter “Yamazaki”) in view of Single-Crystal Si-Films via a Low Substrate Temperature Excimer-Laser Crystallization Method by Sposili et al. (hereinafter “Sposili”).

The rejection of claims 27 and 34 as being unpatentable over Yamazaki in view of Sposili is respectfully traversed and reconsideration is requested.

Claim 27 is allowable over Yamazaki in view of Sposili in that the structure of claim 27 recites a combination of elements including, for example, “a driver circuit formed on the first substrate in the second region, the driver circuit having an active layer formed of polycrystalline silicon crystallized from an amorphous silicon deposited directly on the first substrate, the polycrystalline having silicon grains growing by single-pulse lateral growth process” and “a controller unit formed on the first substrate in the third region, wherein the pixel array, driver circuit and controller unit are integrally located on the first substrate, and wherein the controller unit includes an active layer formed of single crystalline silicon in which silicon grains have a length beyond a single-pulse lateral growth distance and is grown from the amorphous silicon by single-pulse lateral growth process.” None of the cited references, singly or in combination, teaches or suggests at least these features of the claimed invention.

Accordingly, applicant respectfully submits that claim 27 and claim 34, which depends from claim 27, are allowable over the cited references.

Applicants believe the foregoing amendments place the application in condition for allowance and early, favorable action is respectfully solicited.

If for any reason the Examiner finds the application other than in condition for allowance, the Examiner is requested to call the undersigned attorney at (202) 496-7500 to discuss the steps necessary for placing the application in condition for allowance. All correspondence should continue to be sent to the below-listed address.

If these papers are not considered timely filed by the Patent and Trademark Office, then a petition is hereby made under 37 C.F.R. §1.136, and any additional fees required under 37 C.F.R. §1.136 for any necessary extension of time, or any other fees required to complete the filing of this response, may be charged to Deposit Account No. 50-0911. Please credit any overpayment to deposit Account No. 50-0911.

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Respectfully submitted,

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